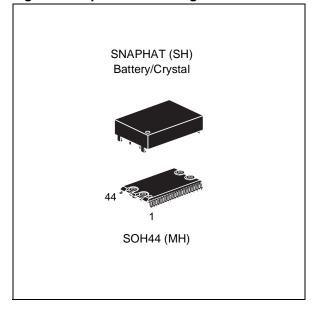


5.0 or 3.3V, 256 Kbit (32 Kbit x 8) TIMEKEEPER® SRAM

FEATURES SUMMARY

- INTEGRATED ULTRA-LOW POWER SRAM, REAL TIME CLOCK, POWER-FAIL CONTROL CIRCUIT, and BATTERY
- FREQUENCY TEST OUTPUT FOR REAL TIME CLOCK SOFTWARE CALIBRATION
- YEAR 2000 COMPLIANT
- AUTOMATIC POWER-FAIL CHIP DESELECT and WRITE PROTECTION
- WATCHDOG TIMER
- WRITE PROTECT VOLTAGE (V_{PFD} = Power-Fail Deselect Voltage):
 - M48T37Y: $V_{CC} = 4.5 \text{ to } 5.5V$ $4.2V \le V_{PFD} \le 4.5V$
 - M48T37V: V_{CC} = 3.0 to 3.6V 2.7V $\leq V_{PFD} \leq 3.0V$
- PACKAGING INCLUDES A 44-LEAD SOIC and SNAPHAT® TOP (to be Ordered Separately)
- SOIC PACKAGE PROVIDES DIRECT CONNECTION FOR A SNAPHAT TOP WHICH CONTAINS THE BATTERY and CRYSTAL
- MICROPROCESSOR POWER-ON RESET (Valid even during battery back-up mode)
- PROGRAMMABLE ALARM OUTPUT ACTIVE IN THE BATTERY BACK-UP MODE
- BATTERY LOW FLAG

Figure 1. 44-pin SOIC Package



March 2003 1/27

TABLE OF CONTENTS

SUMMARY DESCRIPTION	
Figure 2. Logic Diagram	
Table 1. Signal Names	
Figure 3. SOIC Connections	
Figure 4. Block Diagram	
MAXIMUM RATING	6
Table 2. Absolute Maximum Ratings	
DC AND AC PARAMETERS	
Table 3. Operating and AC Measurement Conditions	
Figure 5. AC Testing Load Circuit	
Table 4. Capacitance	
Table 5. DC Characteristics	
OPERATION MODES	
Table 6. Operating Modes	
READ Mode	
Figure 6. READ Mode AC Waveforms	
Table 7. READ Mode AC Characteristics	
WRITE Mode	
Figure 7. WRITE Enable Controlled, WRITE AC Waveform	
Figure 8. Chip Enable Controlled, WRITE AC Waveforms	
WRITE Mode AC Characteristics	
Data Retention Mode	
Figure 9. Power Down/Up Mode AC Waveforms	
Table 9. Power Down/Up AC Characteristics	
Table 10. Power Down/Up Trip Points DC Characteristics	
CLOCK OPERATIONS	14
Reading the Clock	14
Setting the Clock	
Stopping and Starting the Oscillator	
Table 11. Register Map	
Setting the Alarm Clock	
Figure 10. Alarm Interrupt Reset Waveform	
Table 12. Alarm Repeat Modes	
Figure 11. Back-up Mode Alarm Waveforms	
Calibrating the Clock	

	Watchdog Timer	. 18
	Power-on Reset	. 18
	Programmable Interrupts	. 19
	Battery Low Flag	. 19
	Initial Power-on Defaults. Table 13. Default Values. Figure 12. Crystal Accuracy Across Temperature. Figure 13. Clock Calibration.	. 19 . 20
	V _{CC} Noise And Negative Going Transients	. 21 . 21
PΑ	CKAGE MECHANICAL INFORMATION	. 22
PA	RT NUMBERING	
D =	WISION HISTORY	26

SUMMARY DESCRIPTION

The M48T37Y/V TIMEKEEPER® RAM is a 32 Kb x8 non-volatile static RAM and real time clock. The monolithic chip is available in a special package which provides a highly integrated battery backed-up memory and real time clock solution.

The 44-lead, 330mil SOIC package provides sockets with gold-plated contacts at both ends for direct connection to a separate SNAPHAT housing containing the battery and crystal. The unique design allows the SNAPHAT® battery/crystal package to be mounted on top of the SOIC package after the completion of the surface mount process. Insertion of the SNAPHAT housing after reflow

prevents potential battery and crystal damage due

Figure 2. Logic Diagram

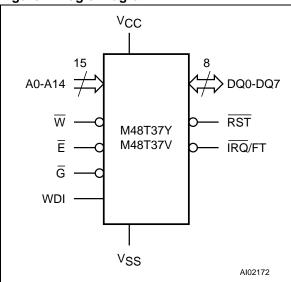


Table 1. Signal Names

A0-A14	Address Inputs
DQ0-DQ7	Data Inputs / Outputs
RST	Reset Output (Open Drain)
ĪRQ/FT	Interrupt / Frequency Test Output (Open Drain)
WDI	Watchdog Input
Ē	Chip Enable
G	Output Enable
W	WRITE Enable
V _{CC}	Supply Voltage
V _{SS}	Ground
NC	Not connected Internally

to the high temperatures required for device surface-mounting. The SNAPHAT housing is keyed to prevent reverse insertion.

The SOIC and battery packages are shipped separately in plastic anti-static tubes or in Tape &Reel form. For the 44-lead SOIC, the battery/crystal package (e.g., SNAPHAT) part number is "M4T28-BR12SH" or "M4T32-BR12SH" (see Table 18, page 25).

Caution: Do not place the SNAPHAT battery/crystal top in conductive foam, as this will drain the lithium button-cell battery.

Figure 3. SOIC Connections

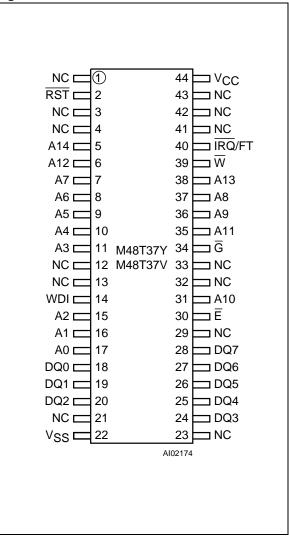
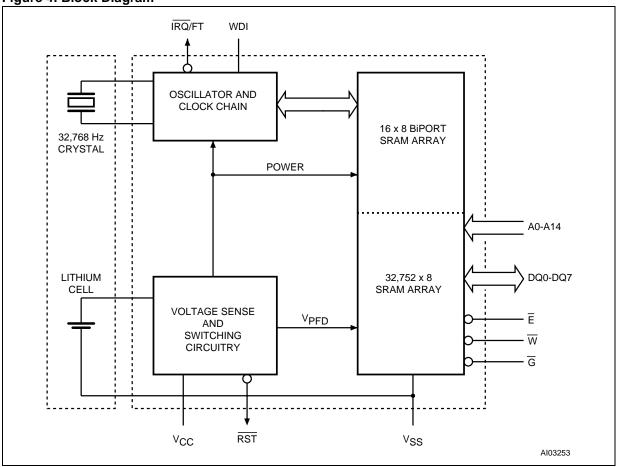


Figure 4. Block Diagram



MAXIMUM RATING

Stressing the device above the rating listed in the "Absolute Maximum Ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is

not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

Table 2. Absolute Maximum Ratings

Symbol	Parameter		Value	Unit
T _A	Ambient Operating Temperature	Grade 1	0 to 70	°C
'A	Ambient Operating Temperature	Grade 6	-40 to 85	°C
T _{STG}	Storage Temperature (V _{CC} Off, Oscillator	SNAPHAT [®]	-40 to 85	°C
1316	Off)	SOIC	-55 to 125	°C
T _{SLD} (1)	Lead Solder Temperature for 10 seconds		260	°C
V _{IO}	Input or Output Voltages	M48T37Y	-0.3 to 7	V
VIO	Imput of Output Voltages	M48T37V	-0.3 to 4.6	V
V _{CC}	Supply Voltage	M48T37Y	-0.3 to 7	V
VCC	Supply voltage	M48T37V	-0.3 to 4.6	V
Io	Output Current		10	mA
PD	Power Dissipation		1	W

Note: 1. Reflow at peak temperature of 215°C to 225°C for < 60 seconds (total thermal budget not to exceed 180°C for between 90 to 120 seconds).

CAUTION: Negative undershoots below -0.3V are not allowed on any pin while in the Battery Back-up mode.

CAUTION: Do NOT wave solder SOIC to avoid damaging SNAPHAT sockets.

DC AND AC PARAMETERS

This section summarizes the operating and measurement conditions, as well as the DC and AC characteristics of the device. The parameters in the following DC and AC Characteristic tables are derived from tests performed under the Measure-

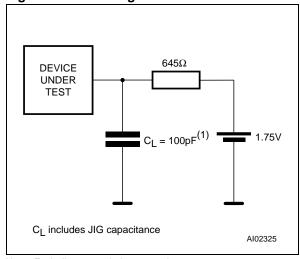
ment Conditions listed in the relevant tables. Designers should check that the operating conditions in their projects match the measurement conditions when using the quoted parameters.

Table 3. Operating and AC Measurement Conditions

Parameter	M48T37Y	M48T37V	Unit	
Supply Voltage (V _{CC})		4.5 to 5.5	3.0 to 3.6	V
Ambient Operating Temperature (T _A)	Grade 1	0 to 70	0 to 70	°C
Ambient Operating Temperature (TA)	Grade 6	-40 to 85	-40 to 85	°C
Load Capacitance (C _L)		100	50	pF
Input Rise and Fall Times		≤ 10	≤10	ns
Input Pulse Voltages		0 to 3	0 to 3	V
Input and Output Timing Ref. Voltages		1.5	1.5	V

Note: Output Hi-Z is defined as the point where data is no longer driven.

Figure 5. AC Testing Load Circuit



Note: Excluding open-drain output pins

1. ; 50pF for M48T37V.

Table 4. Capacitance

Symbol	Parameter ^(1,2)	Min	Max	Unit
C _{IN}	Input Capacitance		10	pF
C _{IO} (3)	Input / Output Capacitance		10	pF

Note: 1. Effective capacitance measured with power supply at 5V. Sampled only, not 100% tested.

- 2. At 25°C, f = 1MHz.
- 3. Outputs deselected.



Table 5. DC Characteristics

			M48	T37Y	M48T37V -100		Unit
Symbol	Parameter Te	Test Condition ⁽¹⁾	-70				
			Min	Max	Min	Max	
I _{LI} ⁽²⁾	Input Leakage Current	$0V \le V_{IN} \le V_{CC}$		±1		±1	μA
I _{LO} ⁽²⁾	Output Leakage Current	$0V \le V_{OUT} \le V_{CC}$		±1		±1	μA
I _{CC}	Supply Current	Outputs open		50		33	mA
I _{CC1}	Supply Current (Standby) TTL	E = V _{IH}		3		2	mA
I _{CC2}	Supply Current (Standby) CMOS	$\overline{E} = V_{CC} - 0.2V$		3		2	mA
V _{IL} ⁽³⁾	Input Low Voltage		-0.3	0.8	-0.3	0.8	V
V _{IH}	Input High Voltage		2.2	V _{CC} + 0.3	2.2	V _{CC} + 0.3	V
Voi	Output Low Voltage (standard)	I _{OL} = 2.1mA		0.4		0.4	V
VoL	Output Low Voltage (open drain)	I _{OL} = 10mA		0.4		0.4	V
V _{OH} ⁽³⁾	Output High Voltage	I _{OH} = -1mA	2.4		2.4		V

Note: 1. Valid for Ambient Operating Temperature: T_A = 0 to 70°C or -40 to 85°C; V_{CC} = 4.5 to 5.5V or 3.0 to 3.6V (except where noted).

2. Outputs deselected.

3. Negative spikes of -1V allowed for up to 10ns once per cycle.

OPERATION MODES

As Figure 4, page 5 shows, the static memory array and the quartz controlled clock oscillator of the M48T37Y/V are integrated on one silicon chip. The memory locations that provide user accessible BYTEWIDE™ clock information are in the bytes with addresses 7FF1 and 7FF9h-7FFFh (located in Table 11, page 15). The clock locations contain the century, year, month, date, day, hour, minute, and second in 24 hour BCD format. Corrections for 28, 29 (leap year - valid until the year 2100), 30, and 31 day months are made automatically.

Byte 7FF8h is the clock control register. This byte controls user access to the clock information and also stores the clock calibration setting.

Byte 7FF7h contains the watchdog timer setting. The watchdog timer redirects an out-of-control microprocessor and provides a reset or interrupt to it. Bytes 7FF2h-7FF5h are reserved for clock alarm programming. These bytes can be used to set the alarm. This will generate an active low signal on

the IRQ/FT pin when the alarm bytes match the date, hours, minutes, and seconds of the clock. The eight clock bytes are not the actual clock counters themselves; they are memory locations consisting of BiPORT™ READ/WRITE memory cells. The M48T37Y/V includes a clock control circuit which updates the clock bytes with current information once per second. The information can be accessed by the user in the same manner as any other location in the static memory array.

The M48T37Y/V also has its own Power-fail Detect circuit. The control circuitry constantly monitors the single V_{CC} supply for an out of tolerance condition. When V_{CC} is out of tolerance, the circuit write protects the SRAM, providing a high degree of data security in the midst of unpredictable system operation brought on by low V_{CC} . As V_{CC} falls below the Battery Back-up Switchover Voltage $(V_{SO}),\,$ the control circuitry connects the battery which maintains data and clock operation until valid power returns.

Table 6. Operating Modes

Mode	V _{CC}	Ē	G	w	DQ0-DQ7	Power
Deselect		V _{IH}	Х	Х	High Z	Standby
WRITE	4.5 to 5.5V	V _{IL}	Х	V _{IL}	D _{IN}	Active
READ	or 3.0 to 3.6V	V _{IL}	V _{IL}	V _{IH}	D _{OUT}	Active
READ		VIL	VIH	V _{IH}	High Z	Active
Deselect	V _{SO} to V _{PFD} (min) ⁽¹⁾	Х	Х	Х	High Z	CMOS Standby
Deselect	≤ V _{SO} ⁽¹⁾	Х	Х	Х	High Z	Battery Back-up Mode

Note: $X = V_{IH}$ or V_{II} ; $V_{SO} = Battery Back-up Switchover Voltage.$

^{1.} See Table 10, page 14 for details.

READ Mode

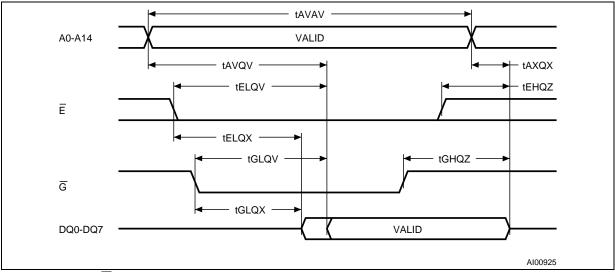
The M48T37Y/V is in the READ Mode whenever WRITE Enable (W) is high and Chip Enable (E) is low. The unique address specified by the 15 Address Inputs defines which one of the 32,752 bytes of data is to be accessed. Valid data will be available at the Data I/O pins within Address Access time (tavQv) after the last address input signal is stable, providing that the E and Output Enable (G) access times are also satisfied. If the E and G access times are not met, valid data will be available

after the latter of the Chip Enable Access time (t_{ELQV}) or Output Enable Access time (t_{GLQV}).

The state of the eight three-state Data I/O signals is controlled by \overline{E} and \overline{G} . If the outputs are activated before t_{AVQV} , the data lines will be driven to an indeterminate state until t_{AVQV} .

If the Address Inputs are changed while E and G remain active, output data will remain valid for Output Data Hold time (t_{AXQX}) but will be indeterminate until the next Address Access.

Figure 6. READ Mode AC Waveforms



Note: WRITE Enable (\overline{W}) = High.

Table 7. READ Mode AC Characteristics

		M48T37Y -70		M48T37V -100		Unit
Symbol	Parameter ⁽¹⁾					
		Min	Max	Min	Max	
t _{AVAV}	READ Cycle Time	70		100		ns
t _{AVQV}	Address Valid to Output Valid		70		100	ns
t _{ELQV}	Chip Enable Low to Output Valid		70		100	ns
t _{GLQV}	Output Enable Low to Output Valid		35		50	ns
t _{ELQX} (2)	Chip Enable Low to Output Transition	5		10		ns
t _{GLQX} (2)	Output Enable Low to Output Transition	5		5		ns
t _{EHQZ} (2)	Chip Enable High to Output Hi-Z		25		50	ns
t _{GHQZ} (2)	Output Enable High to Output Hi-Z		25		40	ns
t _{AXQX}	Address Transition to Output Transition	10		10		ns

Note: 1. Valid for Ambient Operating Temperature: $T_A = 0$ to $70^{\circ}C$ or -40 to $85^{\circ}C$; $V_{CC} = 4.5$ to 5.5V or 3.0 to 3.6V (except where noted). 2. $C_L = 5pF$.

WRITE Mode

The M48T37Y/V is in the WRITE Mode whenever \overline{W} and \overline{E} are low. The start of a WRITE is referenced from the latter occurring falling edge of \overline{W} or \overline{E} . A WRITE is terminated by the earlier rising edge of \overline{W} or \overline{E} . The addresses must be held valid throughout the cycle. \overline{E} or \overline{W} must return high for a minimum of \overline{E} from Chip Enable or \overline{E} twhax from WRITE Enable prior to the initiation of anoth-

er READ or WRITE cycle. Data-in must be valid t_{D-VWH} prior to the end of WRITE and remain valid for t_{WHDX} afterward. \overline{G} should be kept high during WRITE cycles to avoid bus contention; however, if the output bus has been activated by a low on \overline{E} and \overline{G} , a low on \overline{W} will disable the outputs t_{WLQZ} after \overline{W} falls.

Figure 7. WRITE Enable Controlled, WRITE AC Waveform

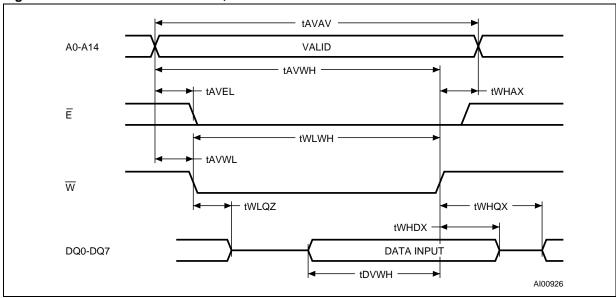


Figure 8. Chip Enable Controlled, WRITE AC Waveforms

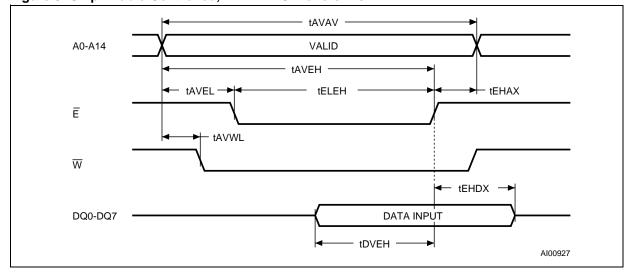


Table 8. WRITE Mode AC Characteristics

		M48T37Y -70		M48T37V -100		Unit
Symbol	Parameter ⁽¹⁾					
		Min	Max	Min	Max	
t _{AVAV}	WRITE Cycle Time	70		100		ns
t _{AVWL}	Address Valid to WRITE Enable Low	0		0		ns
t _{AVEL}	Address Valid to Chip Enable Low	0		0		ns
t _{WLWH}	WRITE Enable Pulse Width	50		80		ns
teleh	Chip Enable Low to Chip Enable High	55		80		ns
t _{WHAX}	WRITE Enable High to Address Transition	0		10		ns
t _{EHAX}	Chip Enable High to Address Transition	0		10		ns
t _{DVWH}	Input Valid to WRITE Enable High	30		50		ns
t _{DVEH}	Input Valid to Chip Enable High	30		50		ns
t _{WHDX}	WRITE Enable High to Input Transition	5		5		ns
t _{EHDX}	Chip Enable High to Input Transition	5		5		ns
t _{WLQZ} (2,3)	WRITE Enable Low to Output Hi-Z		25		50	ns
t _{AVWH}	Address Valid to WRITE Enable High	60		80		ns
taveh	Address Valid to Chip Enable High	60		80		ns
t _{WHQX} (2,3)	WRITE Enable High to Output Transition	5		10		ns

Note: 1. Valid for Ambient Operating Temperature: T_A = 0 to 70°C or -40 to 85°C; V_{CC} = 4.5 to 5.5V or 3.0 to 3.6V (except where noted).

2. C_L = 5pF.

3. If E goes low simultaneously with W going low, the outputs remain in the high impedance state.

Data Retention Mode

With valid V_{CC} applied, the M48T37Y/V operates as a conventional BYTEWIDETM static RAM. Should the Supply Voltage decay, the RAM will automatically power-fail deselect, write protecting itself when V_{CC} falls within the V_{PFD} (max), V_{PFD} (min) window. All outputs become high impedance, and all inputs are treated as "Don't care."

Note: A power failure during a WRITE cycle may corrupt data at the currently addressed location, but does not jeopardize the rest of the RAM's content. At voltages below V_{PFD} (min), the user can be assured the memory will be in a write protected state, provided the V_{CC} fall time is not less than t_F .

The M48T37Y/V may respond to transient noise spikes on V_{CC} that reach into the deselect window

during the time the device is sampling V_{CC} . Therefore, decoupling of the power supply lines is recommended.

When V_{CC} drops below V_{SO} , the control circuit switches power to the internal battery which preserves data and powers the clock. The internal button cell will maintain data in the M48T37Y/V for an accumulated period of at least 7 years at room temperature when V_{CC} is less than V_{SO} . As system power returns and V_{CC} rises above V_{SO} , the battery is disconnected and the power supply is switched to external V_{CC} . Normal RAM operation can resume t_{REC} after V_{CC} reaches V_{PFD} (max).

For more information on Battery Storage Life refer to the Application Note AN1012.

Figure 9. Power Down/Up Mode AC Waveforms

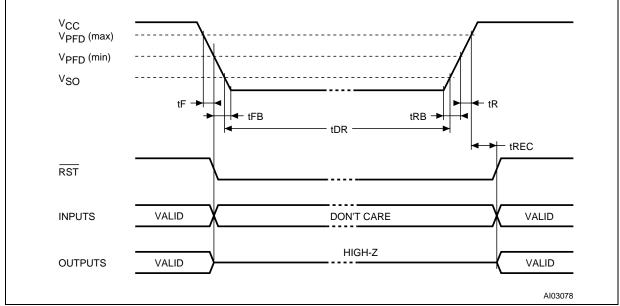


Table 9. Power Down/Up AC Characteristics

Symbol	Parameter ⁽¹⁾	Min	Max	Unit
t _F ⁽²⁾	V _{PFD} (max) to V _{PFD} (min) V _{CC} Fall Time	300		μs
t _{FB} ⁽³⁾	V _{PFD} (min) to V _{SS} V _{CC} Fall Time	10		μs
t _R	V _{PFD} (min) to V _{PFD} (max) V _{CC} Rise Time	10		μs
t _{RB}	V _{SS} to V _{PFD} (min) V _{CC} Rise Time	1		μs
t _{REC} ⁽⁴⁾	V _{PFD} (max) to RST High	40	200	ms

Note: 1. Valid for Ambient Operating Temperature: T_A = 0 to 70°C or -40 to 85°C; V_{CC} = 4.5 to 5.5V or 3.0 to 3.6V (except where noted).

^{4.} t_{REC} (min) = 20ms for Industrial Temperature Range - Grade 6 device.



V_{PFD} (max) to V_{PFD} (min) fall time of less than tF may result in deselection/write protection not occurring until 200µs after V_{CC} passes V_{PFD} (min).

^{3.} V_{PFD} (min) to V_{SS} fall time of less than t_{FB} may cause corruption of RAM data.

Table 10. Power Down/Up Trip Points DC Characteristics

Symbol	Parameter ⁽¹⁾	Min	Тур	Max	Unit	
V _{PFD}	Power-fail Deselect Voltage	M48T37Y	4.2	4.4	4.5	V
		M48T37V	2.7	2.9	3.0	V
V _{SO}	Battery Back-up Switchover Voltage	M48T37Y		V_{BAT}		V
		M48T37V		V _{PFD} –100mV		V
t _{DR} ⁽³⁾	Expected Data Retention Time	Grade 1	5	7		YEARS
		Grade 6	10 ⁽²⁾			YEARS

Note: All voltages referenced to VSS.

- 1. Valid for Ambient Operating Temperature: T_A = 0 to 70°C or -40 to 85°C; V_{CC} = 4.5 to 5.5V or 3.0 to 3.6V (except where noted).
- 2. Using larger M4T32-BR12SH6 SNAPHAT top (recommended for Industrial Temperature Range Grade 6 device).
- 3. At 25°C, $V_{CC} = 0V$.

CLOCK OPERATIONS

Reading the Clock

Updates to the TIMEKEEPER[®] registers should be halted before clock data is read to prevent reading data in transition. The BiPORT™ TIME-KEEPER cells in the RAM array are only data registers and not the actual clock counters, so updating the registers can be halted without disturbing the clock itself.

Updating is halted when a '1' is written to the READ Bit, D6 in the Control Register 7FF8h. As long as a '1' remains in that position, updating is halted. After a halt is issued, the registers reflect the count; that is, the day, date, and the time that were current at the moment the halt command was issued.

All of the TIMEKEEPER registers are updated simultaneously. A halt will not interrupt an update in progress. Updating will resume within a second after the bit is reset to a '0.'

Setting the Clock

Bit D7 of the Control Register (7FF8h) is the WRITE Bit. Setting the WRITE Bit to a '1,' like the READ Bit, halts updates to the TIMEKEEPER registers. The user can then load them with the cor-

rect day, date, and time data in 24 hour BCD format (see Table 11, page 15). Resetting the WRITE Bit to a '0' then transfers the values of all time registers (7FF1h, 7FF9h-7FFh) to the actual TIMEKEEPER counters and allows normal operation to resume. After the WRITE Bit is reset, the next clock update will occur in approximately one second.

Note: Upon power-up following a power failure, both the WRITE Bit and the READ Bit will be reset to '0.'

Stopping and Starting the Oscillator

The oscillator may be stopped at any time. If the device is going to spend a significant amount of time on the shelf, the oscillator can be turned off to minimize current drain on the battery. The STOP Bit is the MSB of the seconds register. Setting it to a '1' stops the oscillator. When reset to a '0,' the M48T37Y/V oscillator starts within one second.

Note: It is not necessary to set the WRITE Bit when setting or resetting the FREQUENCY TEST Bit (FT) or the STOP Bit (ST).

Table 11. Register Map

A -l -l		Data								Function/Range	
Address	D7	D6	D5	D4	D3	D2	D1	D0	BCD Format		
7FFFh		10 Y	'ears			Ye	ear		Year	00-99	
7FFEh	0	0	0	10 M		Мо	nth		Month	01-12	
7FFDh	0	0	10 [Date		Date: Day	of Month		Date	01-31	
7FFCh	0	FT	0	0	0	D	ay of Wee	ek	Day	01-7	
7FFBh	0	0	10 H	lours	Hours			Hours	00-23		
7FFAh	0	,	10 Minutes	S	Minutes				Min	00-59	
7FF9h	ST	1	0 Second	s	s Seconds				Sec	00-59	
7FF8h	W	R	S		(Calibration	า		Control		
7FF7h	WDS	BMB4	BMB3	BMB2	BMB1	BMB0	RB1	RB0	Watchdog		
7FF6h	AFE	0	ABE	0	0	0	0	0	Interrupts		
7FF5h	RPT4	0	Alarm '	10 Date		Alarm	Date		Alarm Date	01-31	
7FF4h	RPT3	0	Alarm 1	0 Hours	Alarm Hours		Alarm Hour	00-23			
7FF3h	RPT2	Alaı	m 10 Min	utes	Alarm Minutes				Alarm Min	00-59	
7FF2h	RPT1	Alar	m 10 Seco	onds	Alarm Seconds				Alarm Sec	00-59	
7FF1h		1000	Year		100 Year			Century	00-99		
7FF0h	WDF	AF	Z	BL	Z	Z	Z	Z	Flags		

Keys: S = Sign Bit

FT = Frequency Test Bit

R = READ Bit

W = WRITE Bit

ST = Stop Bit

0 = Must be set to '0'

BL = Battery Low Flag (Read only)

BMB0-BMB4 = Watchdog Multiplier Bits

AFE = Alarm Flag Enable Flag RB0-RB1 = Watchdog Resolution Bits

WDS = Watchdog Steering Bit

ABE = Alarm in Battery Back-Up Mode Enable Bit

RPT1-RPT4 = Alarm Repeat Mode Bits

WDF = Watchdog Flag (Read only)

AF = Alarm Flag (Read only)

Z = '0' and are Read only

Setting the Alarm Clock

Registers 7FF5h-7FF2h contain the alarm settings. The alarm can be configured to go off at a predetermined time on a specific day of the month or repeat every day, hour, minute, or second. It can also be programmed to go off while the M48T37Y/V is in the battery back-up mode of operation to serve as a system wake-up call.

RPT1-RPT4 put the alarm in the repeat mode of operation. Table 12 shows the possible configurations. Codes not listed in the table default to the once per second mode to quickly alert the user of an incorrect alarm setting.

Note: User must transition address (or toggle chip enable) to see Flag Bit change.

When the clock information matches the alarm clock settings based on the match criteria defined by RPT1-RPT4, AF is set. If <u>AFE</u> is also set, the alarm condition activates the <u>IRQ/FT</u> pin. To dis-

able alarm, write '0' to the Alarm Date registers and RPT1-4. The alarm flag and the IRQ/FT output are cleared by a READ to the Flags Register as shown in Figure 10. A subsequent READ of the Flags Register is necessary to see that the value of the Alarm Flag has been reset to '0.'

The IRQ/FT pin can also be activated in the battery back-up mode. The IRQ/FT will go low if an alarm occurs and both the Alarm in Battery Back-up Mode Enable (ABE) and the AFE are set. The ABE and AFE bits are reset during power-up, therefore an alarm generated during power-up will only set AF. The user can read the Flag Register at system boot-up to determine if an alarm was generated while the M48T37Y/V was in the deselect mode during power-up. Figure 11, page 17 illustrates the back-up mode alarm timing.

Figure 10. Alarm Interrupt Reset Waveform

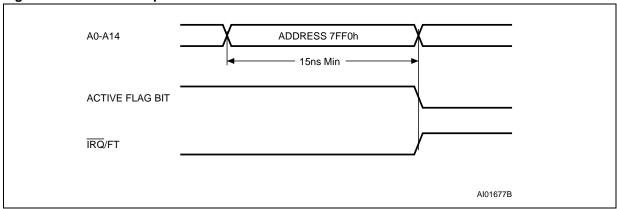


Table 12. Alarm Repeat Modes

RPT4	RPT3	RPT2	RPT1	Alarm Activated
1	1	1	1	Once per Second
1	1	1	0	Once per Minute
1	1	0	0	Once per Hour
1	0	0	0	Once per Day
0	0	0	0	Once per Month

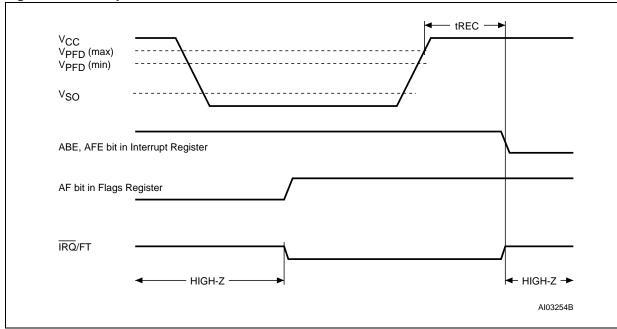


Figure 11. Back-up Mode Alarm Waveforms

Calibrating the Clock

The M48T37Y/V is driven by a quartz controlled oscillator with a nominal frequency of 32,768 Hz. The devices are tested not to exceed ±35 PPM (parts per million) oscillator frequency error at 25 °C, which equates to about ±1.53 minutes per month. With the calibration bits properly set, the accuracy of each M48T37Y/V improves to better than +1/–2 PPM at 25 °C.

The oscillation rate of any crystal changes with temperature (see Figure 12, page 20). Most clock chips compensate for crystal frequency and temperature shift error with cumbersome trim capacitors. The M48T37Y/V design, however, employs periodic counter correction. The calibration circuit adds or subtracts counts from the oscillator divider circuit at the divide by 256 stage, as shown in Figure 13, page 20. The number of times pulses are blanked (subtracted, negative calibration) or split (added, positive calibration) depends upon the value loaded into the five-bit Calibration byte found in the Control Register. Adding counts speeds the clock up, subtracting counts slows the clock down.

The Calibration Byte occupies the five lower order bits (D4-D0) in the Control Register 7FF8h. These bits can be set to represent any value between 0 and 31 in binary form. Bit D5 is the Sign Bit; '1' indicates positive calibration, '0' indicates negative calibration. Calibration occurs within a 64 minute cycle. The first 62 minutes in the cycle may, once

per minute, have one second either shortened by 128 or lengthened by 256 oscillator cycles. If a binary '1' is loaded into the register, only the first 2 minutes in the 64 minute cycle will be modified; if a binary 6 is loaded, the first 12 will be affected, and so on.

Therefore, each calibration step has the effect of adding 512 or subtracting 256 oscillator cycles for every 125, 829, 120 (64 minutes x 60 seconds/minute x 32,768 cycles/second) actual oscillator cycles, that is +4.068 or -2.034 PPM of adjustment per calibration step in the calibration register. Assuming that the oscillator is in fact running at exactly 32,768 Hz, each of the 31 increments in the Calibration Byte would represent +10.7 or -5.35 seconds per month which corresponds to a total range of +5.5 or -2.75 minutes per month.

Two methods are available for ascertaining how much calibration a given M48T37Y/V may require. The first involves simply setting the clock, letting it run for a month and comparing it to a known accurate reference (like WWW broadcasts). While that may seem crude, it allows the designer to give the end user the ability to calibrate his clock as his environment may require, even after the final product is packaged in a non-user serviceable enclosure. All the designer has to do is provide a simple utility that accesses the Calibration Byte.

The second approach is better suited to a manufacturing environment, and involves the use of the IRQ/FT pin. The pin will toggle at 512 Hz when the Stop Bit (ST, D7 of 7FF9h) is '0' the Frequency Test Bit (FT, D6 of 7FFCh) is '1,' the Alarm Flag Enable Bit (AFE, D7 of 7FF6h) is '0,' and the Watchdog Steering Bit (WDS, D7 of 7FF7h) is '1' or the Watchdog Register is reset (7FF7h=0).

Any deviation from 512 Hz indicates the degree and direction of oscillator frequency shift at the test temperature. For example, a reading of 512.01024 Hz would indicate a +20 PPM oscillator frequency error, requiring a -10(WR001010) to be loaded into the Calibration Byte for correction.

Note: Setting or changing the Calibration Byte does not affect the Frequency Test output frequency.

The $\overline{IRQ/FT}$ pin is an open drain output which requires a pull-up resistor for proper operation. A 500-10k Ω resistor is recommended in order to control the rise time. The FT Bit is cleared on power-down.

For more information on calibration, see the Application Note AN934, "TIMEKEEPER Calibration."

Watchdog Timer

The watchdog timer can be used to detect an out-of-control microprocessor. The user programs the watchdog timer by setting the desired amount of time-out into the eight-bit Watchdog Register, address 7FF7h. The five bits (BMB4-BMB0) that store a binary multiplier and the two lower order bits (RB1-RB0) select the resolution, where $00 = \frac{1}{16}$ second, $01 = \frac{1}{4}$ second, 10 = 1 second, and 11 = 4 seconds. The amount of time-out is then determined to be the multiplication of the five-bit multiplier value with the resolution. (For example: writing 00001110 in the Watchdog Register = 3x1, or 3 seconds).

Note: Accuracy of timer is within \pm the selected resolution.

If the processor does not reset the timer within the specified period, the M48T37Y/V sets the Watchdog Flag (WDF) and generates a watchdog inter-

rupt or a microprocessor reset. WDF is reset by reading the Flags Register (Address 7FF0h).

Note: User must transition address (or toggle chip enable) to see Flag Bit change.

Reset will not occur unless the addresses are stable at the flag location for at least 15ns while the device is in the READ Mode as shown in Figure 14, page 21.

The most significant bit of the Watchdog Register is the Watchdog Steering Bit. When set to a '0,' the watchdog will activate the IRQ/FT pin when timedout. When WDS is set to a '1,' the watchdog will output a negative pulse on the RST pin for a duration of trec. The Watchdog Register, the FT Bit, AFE Bit, and ABE Bit will reset to a '0' at the end of a Watchdog time-out when the WDS bit is set to a '1.'

The watchdog timer resets when the microprocessor performs a re-write of the Watchdog Register or an edge transition (low to high / high to low) on the WDI pin occurs. The time-out period then starts over.

The watchdog timer is disabled by writing a value of 00000000 to the eight bits in the Watchdog Register. Should the watchdog timer time-out, a value of 00h needs to be written to the Watchdog Register in order to clear the IRQ/FT pin.

The watchdog function is automatically disabled upon power-down and the Watchdog Register is clea<u>red</u>. If the watchdog function is set to output to the IRQ/FT pin and the frequency test function is activated, the watchdog or alarm function prevails and the frequency test function is denied. The WDI pin should be connected to V_{SS} if not used.

Power-on Reset

The M48T37Y/V continuously monitors V_{CC} . When V_{CC} falls to the power fail detect trip point, the RST pulls low (open drain) and remains <u>low</u> on power-up for t_{REC} after V_{CC} passes V_{PFD} . RST is valid for all V_{CC} conditions. The RST pin is an open drain output and an appropriate resistor to V_{CC} should be chosen to control rise time (see Figure 9, page 13).

Programmable Interrupts

The M48T37Y/V provides two programmable interrupts: an alarm and a watchdog. When an interrupt condition occurs, the M48T37Y/V sets the appropriate flag bit in the Flag Register 7FF0h. The interrupt enable bits (AFE and ABE) in 7FF6h and the Watchdog Steering (WDS) Bit in 7FF7h allow the interrupt to activate the IRQ/FT pin.

The Alarm flag and the IRQ/FT output are cleared by a READ to the Flags Register. An interrupt condition reset will not occur unless the addresses are stable at the flag location for at least 15ns while the device is in the READ Mode as shown in Figure 10, page 16.

The IRQ/FT pin is an open drain output and requires a pull-up resistor ($10k\Omega$ recommended) to V_{CC}. The pin remains in the high impedance state unless an interrupt occurs or the Frequency Test Mode is enabled.

Battery Low Flag

The M48T37Y/V automatically performs periodic battery voltage monitoring upon power-up. The Battery Low Flag (BL), Bit D4 of the Flags Register 7FF0h, will be asserted high if the SNAPHAT® battery is found to be less than approximately 2.5V. The BL Flag will remain active until completion of battery replacement and subsequent bat-

tery low monitoring tests during the next power-up sequence.

If a battery low is generated during a power-up sequence, this indicates the battery voltage is below 2.5V (approximately), which may be insufficient to maintain data integrity. Data should be considered suspect and verified as correct. A fresh battery should be installed. The SNAPHAT top may be replaced while VCC is applied to the device.

Note: This will cause the clock to lose time during the interval the battery/crystal is removed.

Note: Battery monitoring is a useful technique only when performed periodically. The M48T37Y/V only monitors the battery when a nominal V_{CC} is applied to the device. Thus applications which require extensive durations in the battery back-up mode should be powered-up periodically (at least once every few months) in order for this technique to be beneficial. Additionally, if a battery low is indicated, data integrity should be verified upon power-up via a checksum or other technique.

Initial Power-on Defaults

Upon application of power to the device, the following register bits are set to a '0' state: WDS; BMB0-BMB4; RB0-RB1; AFE; ABE; W; R; and FT (see Table 13).

Table 13. Default Values

Condition	w	R	FT	AFE	ABE	WATCHDOG Register ⁽¹⁾
Initial Power-up (Battery Attach for SNAPHAT) ⁽²⁾	0	0	0	0	0	0
Subsequent Power-up / RESET ⁽³⁾	0	0	0	0	0	0
Power-down ⁽⁴⁾	0	0	0	1	1	0

Note: 1. WDS, BMB0-BMB4, RBO, RB1.

- State of other control bits undefined.
- 3. State of other control bits remains unchanged.
- 4. Assuming these bits set to '1' prior to power-down.



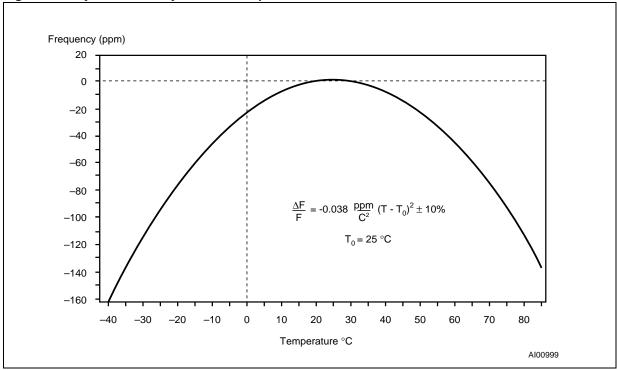
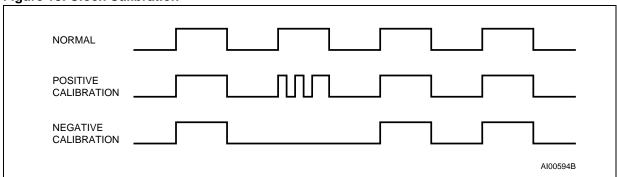


Figure 13. Clock Calibration

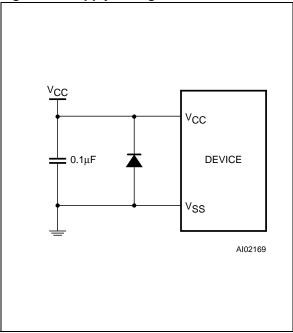


V_{CC} Noise And Negative Going Transients

 I_{CC} transients, including those produced by output switching, can produce voltage fluctuations, resulting in spikes on the V_{CC} bus. These transients can be reduced if capacitors are used to store energy which stabilizes the V_{CC} bus. The energy stored in the bypass capacitors will be released as low going spikes are generated or energy will be absorbed when overshoots occur. A ceramic bypass capacitor value of $0.1\mu F$ (as shown in Figure 14) is recommended in order to provide the needed filtering.

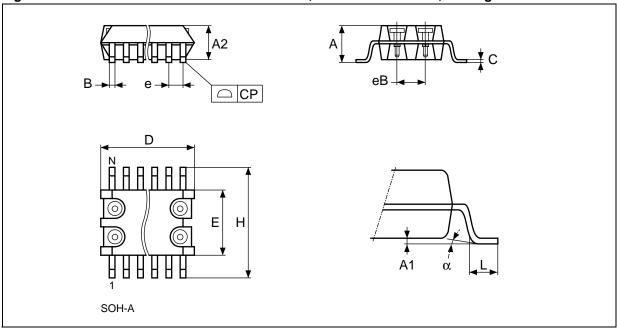
In addition to transients that are caused by normal SRAM operation, power cycling can generate negative voltage spikes on V_{CC} that drive it to values below V_{SS} by as much as one volt. These negative spikes can cause data corruption in the SRAM while in battery backup mode. To protect from these voltage spikes, it is recommended to connect a schottky diode from V_{CC} to V_{SS} (cathode connected to V_{CC} , anode to V_{SS}). Schottky diode 1N5817 is recommended for through hole and MBRS120T3 is recommended for surface mount.

Figure 14. Supply Voltage Protection



PACKAGE MECHANICAL INFORMATION

Figure 15. SOH44 – 44-lead Plastic Small Outline, 4-socket SNAPHAT, Package Outline



Note: Drawing is not to scale.

Table 14. SOH44 – 44-lead Plastic Small Outline, 4-socket SNAPHAT, Package Mechanical Data

		mm		inches		
Symb	Тур	Min	Max	Тур	Min	Max
А			3.05			0.120
A1		0.05	0.36		0.002	0.014
A2		2.34	2.69		0.092	0.106
В		0.36	0.46		0.014	0.018
С		0.15	0.32		0.006	0.012
D		17.71	18.49		0.697	0.728
Е		8.23	8.89		0.324	0.350
е	0.81	_	-	0.032	_	_
еВ		3.20	3.61		0.126	0.142
Н		11.51	12.70		0.453	0.500
L		0.41	1.27		0.016	0.050
α		0°	8°		0°	8°
N		44	1		44	1
СР			0.10			0.004

Figure 16. SH - 4-pin SNAPHAT Housing for 48mAh Battery & Crystal, Package Outline

Note: Drawing is not to scale.

Table 15. SH - 4-pin SNAPHAT Housing for 48mAh Battery & Crystal, Package Mechanical Data

	. p 0		D ano	. y a c. yetai, i	aonago moona	mour Duta	
S. m.h		mm		inches			
Symb	Тур	Min	Max	Тур	Min	Max	
А			9.78			0.385	
A1		6.73	7.24		0.265	0.285	
A2		6.48	6.99		0.255	0.275	
A3			0.38			0.015	
В		0.46	0.56		0.018	0.022	
D		21.21	21.84		0.835	0.860	
E		14.22	14.99		0.560	0.590	
eA		15.55	15.95		0.612	0.628	
eB		3.20	3.61		0.126	0.142	
L		2.03	2.29		0.080	0.090	

Figure 17. SH - 4-pin SNAPHAT Housing for 120mAh Battery & Crystal, Package Outline

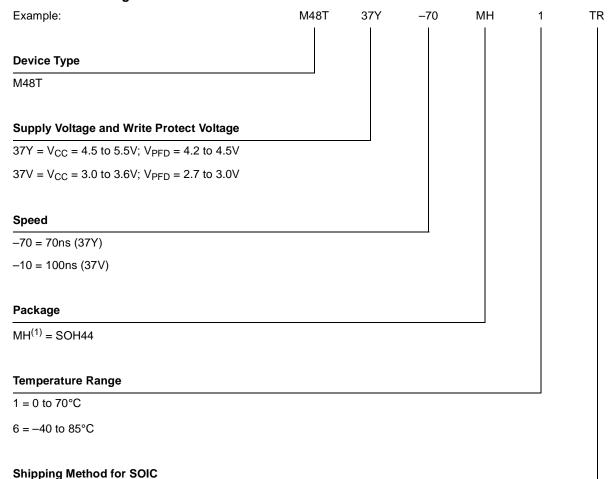
Note: Drawing is not to scale.

Table 16. SH – 4-pin SNAPHAT Housing for 120mAh Battery & Crystal, Package Mechanical Data

Cromb		mm		inches		
Symb	Тур	Min	Max	Тур	Min	Max
А			10.54			0.415
A1		8.00	8.51		0.315	.0335
A2		7.24	8.00		0.285	0.315
A3			0.38			0.015
В		0.46	0.56		0.018	0.022
D		21.21	21.84		0.835	0.860
E		17.27	18.03		0.680	.0710
eA		15.55	15.95		0.612	0.628
eB		3.20	3.61		0.126	0.142
L		2.03	2.29		0.080	0.090

PART NUMBERING

Table 17. Ordering Information Scheme



blank = Tubes

TR = Tape & Reel

Note: 1. The SOIC package (SOH44) requires the battery package (SNAPHAT®) which is ordered separately under the part number "M4TXX-BR12SH" in plastic tube or "M4TXX-BR12SHTR" in Tape & Reel form.

Caution: Do not place the SNAPHAT battery package "M4TXX-BR12SH" in conductive foam as it will drain the lithium button-cell battery.

For a list of available options (e.g., Speed, Package) or for further information on any aspect of this device, please contact the ST Sales Office nearest you.

Table 18. SNAPHAT Battery Table

Part Number	Description	Package
M4T28-BR12SH	Lithium Battery (48mAh) SNAPHAT	SH
M4T32-BR12SH	Lithium Battery (120mAh) SNAPHAT	SH



REVISION HISTORY

Table 19. Document Revision History

Date	Rev. #	Revision Details
December 1999	1.0	First Issue
07-Feb-00	2.0	From Preliminary Data to Data Sheet Battery Low Flag paragraph changed 100ns speed class identifier changed (Tables 7, 8)
11-Jul-00	2.1	t _{FB} changed (Table 9) Watchdog Timer paragraph changed
19-Jun-01	3.0	Reformatted; added temp./voltage info. to tables (Table 4, 5, 7, 8, 9, 10)
06-Aug-01	3.1	Fix text for Setting the Alarm Clock (Figure 10)
15-Jan-02	3.2	Fix footnote numbering (Table 17)
20-May-02	3.3	Modify reflow time and temperature footnote (Table 2)
31-Mar-03	4.0	v2.2 template applied; data retention condition updated (Table 10)

57

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is registered trademark of STMicroelectronics All other names are the property of their respective owners.

© 2003 STMicroelectronics - All Rights Reserved

STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - U.S.A.

www.st.com

